

2SA0720A (2SA720A)

Silicon PNP epitaxial planar type

For low-frequency driver amplification

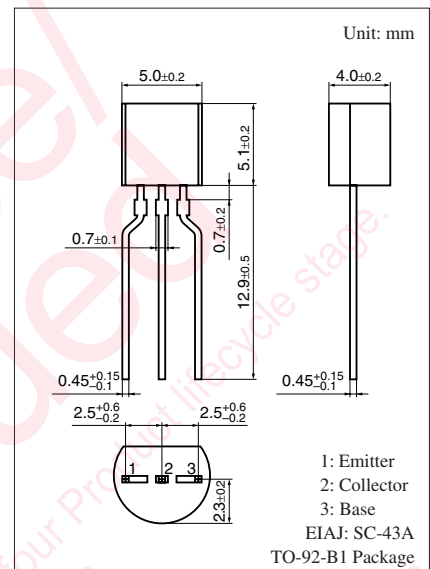
Complementary to 2SC1318A

■ Features

- High collector-emitter voltage (Base open) V_{CEO}
- Optimum for the driver stage of a low-frequency and 25 W to 30 W output amplifier

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|---------------------------------------|-----------|-------------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | -80 | V |
| Collector-emitter voltage (Base open) | V_{CEO} | -70 | V |
| Emitter-base voltage (Collector open) | V_{EBO} | -5 | V |
| Collector current | I_C | -0.5 | A |
| Peak collector current | I_{CP} | -1 | A |
| Collector power dissipation | P_C | 625 | mW |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |



■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--|---------------|--|-----|-------|-------|---------------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_C = -10 \mu\text{A}$, $I_E = 0$ | -80 | | | V |
| Collector-emitter voltage (Base open) | V_{CEO} | $I_C = -2 \text{ mA}$, $I_B = 0$ | -70 | | | V |
| Emitter-base voltage (Collector open) | V_{EBO} | $I_E = -10 \mu\text{A}$, $I_C = 0$ | -5 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{CB} = -20 \text{ V}$, $I_E = 0$ | | | -0.1 | μA |
| Forward current transfer ratio *1 | h_{FE1} *2 | $V_{CE} = -10 \text{ V}$, $I_C = -150 \text{ mA}$ | 85 | | 240 | — |
| | h_{FE2} | $V_{CE} = -10 \text{ V}$, $I_C = -500 \text{ mA}$ | 40 | | | — |
| Collector-emitter saturation voltage *1 | $V_{CE(sat)}$ | $I_C = -300 \text{ mA}$, $I_B = -30 \text{ mA}$ | | -0.2 | -0.6 | V |
| Base-emitter saturation voltage *1 | $V_{BE(sat)}$ | $I_C = -300 \text{ mA}$, $I_B = -30 \text{ mA}$ | | -0.85 | -1.50 | V |
| Transition frequency | f_T | $V_{CB} = -10 \text{ V}$, $I_E = 50 \text{ mA}$, $f = 200 \text{ MHz}$ | | 120 | | MHz |
| Collector output capacitance (Common base, input open circuited) | C_{ob} | $V_{CB} = -10 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$ | | 20 | 30 | pF |

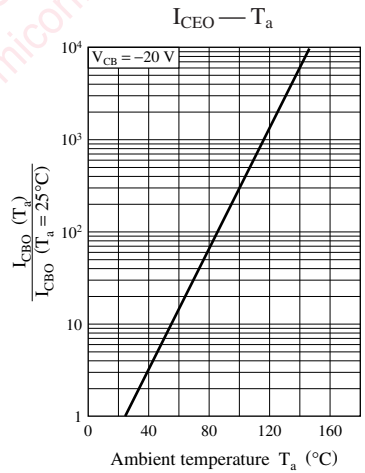
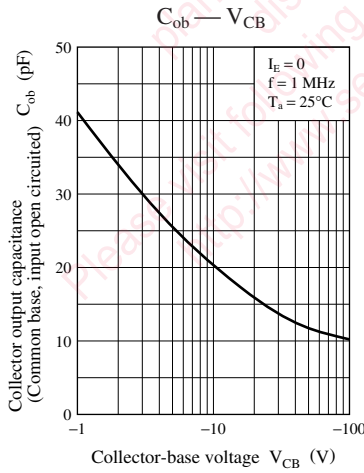
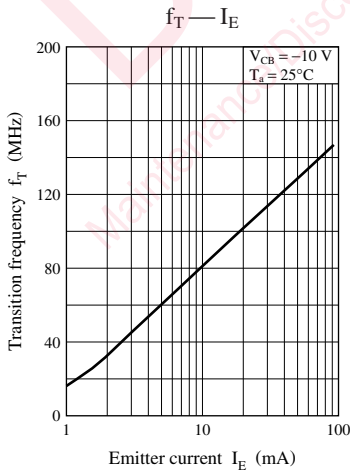
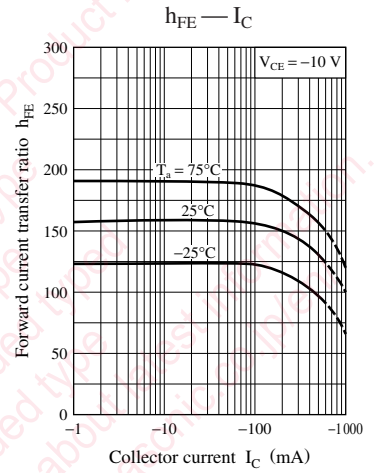
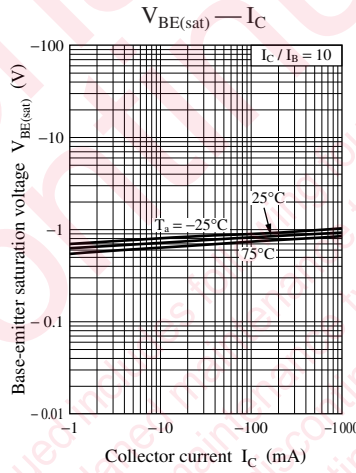
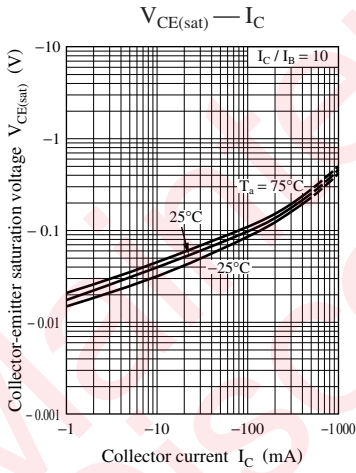
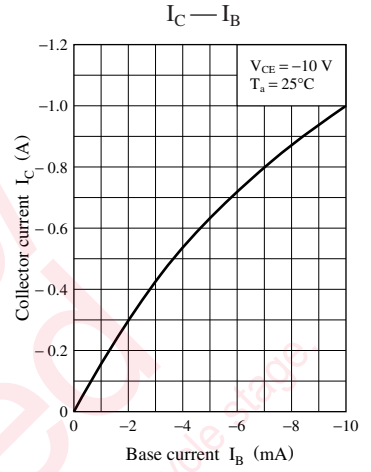
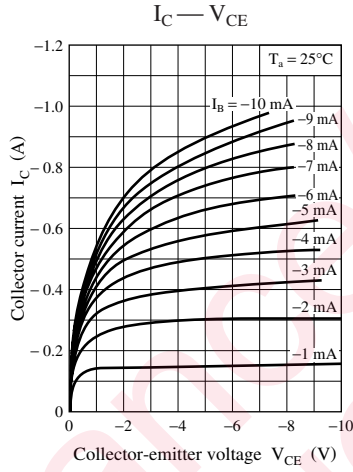
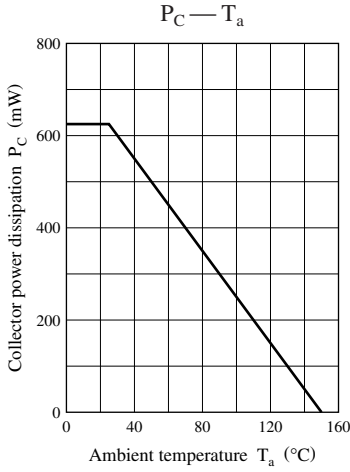
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification

| Rank | Q | R |
|-----------|-----------|------------|
| h_{FE1} | 85 to 170 | 120 to 240 |

Note) The part number in the parenthesis shows conventional part number.



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